

10/033,337

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,781,892 B2
DATED : August 24, 2004
INVENTOR(S) : Hsu et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 4,

Line 6, delete "MOSFET" and insert -- nMOSFET --.

Column 8,

Line 9, delete "in" and insert -- an --.

Column 9,

Line 36, delete " 2^{n-m} " and insert -- 2^m --.

Column 10,

Line 40, delete " 2^{m+} foot" and insert -- 2^{m+k} foot --.

Signed and Sealed this

Third Day of May, 2005

A handwritten signature in black ink, appearing to read "Jon W. Dudas". The signature is stylized with a large, looping initial "J" and a distinct "D" at the end.

JON W. DUDAS
Director of the United States Patent and Trademark Office